

Technical Data Data Sheet N0005, Rev. A **Green Products**

12SQ045 SCHOTTKY BARRIER RECTIFIER

Applications:

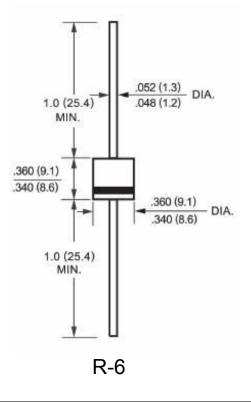
- DC-DC converters
- AC adapter
- High frequency rectification circuit
- Bypass diodes
- Photovoltaic Solar cell Protection Schottky Rectifier

Features:

- Super-high speed & low noise switching
- Low voltage drop
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In Inches/ mm





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Marking Diagram:



Where XXXXX is YYWWL

12	= Forward Current (12A)
S	= Package Type
Q	= Device Type
045	= Reverse Voltage (45V)
SSG	= SSG
ΥY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
12SQ045	R-6 (Pb-Free)	500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Rating:

Characteristics	Symbol	Conditions	Value	Unit
Repetitive Peak Reverse Voltage	VRRM	-	45	V
Max. average forward current	I _{F(AV)}	R- load, Ta=25℃	12	Α
Surge(Non-repetitive) Forward Current	I _{FSM}	8.3ms single half sine-wave	275	А

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Electrical Characteristics (Ta=25°C Unless otherwise specified)

Characteristics	Symbol	Conditions		Max.	Unit
Peak Forward Voltage	Vfm	Іғм=12.0А,Та=25℃		0.55	V
Peak Reverse Current	IRRM1	VRM=VRRM	Ta=25℃	0.5	mA
	IRRM2	VRM-VRRM	Ta=100℃	20	IIIA
Thermal Resistance(Typical)	R θJ-c	Between junction and case		3.0	°C/W
	R ej-l	R BJ-L Between junction and lead		2.0	C/VV

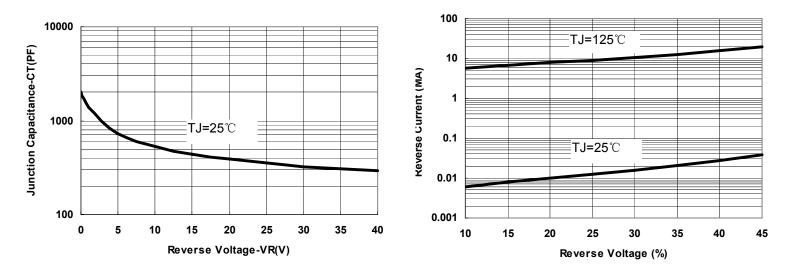
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units	
Max. Junction Temperature at reduced reverse voltage at reduced reverse voltage in DC forward mode	TJ	$V_{ m R}$ ≪80% $V_{ m RRM}$ $V_{ m R}$ ≪50% $V_{ m RRM}$	-55 to +150 -55 to +180 -55 to +200	°C	
Max. Storage Temperature	T _{stg}	-	-55 to +150	°C	
Approximate Weight	wt	-	2.24	g	
Case Style	R-6				

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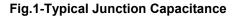


Fig.2-Typical Reverse Characteristics

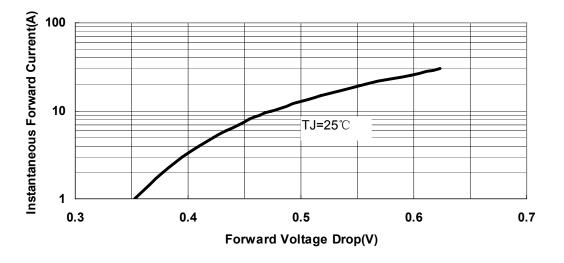


Fig.3-Typical Instantaneous Forward Voltage Characteristics



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